

ScAlMgO4

Magnesium Aluminate Scandium (ScAIMgO₄) Crystal Substrate



DESCRIPTION

 $ScAIMgO_4$ (MgScAIO_4,SCAM) crystals are hexagonal system, has a lattice constant a=0.3246nm, and c=2.5195nm. It has a rhombohedral layered structure similar to that of wurtzite nitride and zinc oxide. It is a new type of substrate material with the smallest lattice mismatch with GaN and ZnO. Its lattice mismatch ratio with GaN is about 1.8%, and the thermal expansion coefficient mismatch with GaN and ZnO epitaxial films is better than sapphire and silicon.

FEATURE

APPLICATION

- Best lattice match with GaN and ZnO
- High transmisson after being polished
- High slope efficiency

- A promising substrate material for GaN epitaxial growth
- Substrates for ZnO films



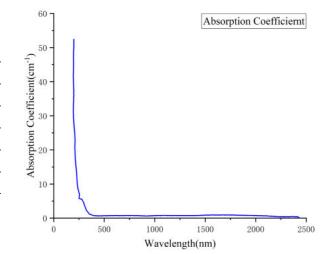


ScAlMgO₄

PARAMETER

Physical and chemicalcharacteristics

Properties	ScMgAlO ₄
Crystal structure	hexagonal crystal system
Lattice constant	a=0.3246nm, c=2.5195nm
Density	3.64g/cm ³
Mohs hardness	4-5Mohs
Thermal expansion coefficient	A=7.45×10 ⁻⁶ /°C



Main Specification

Materials	ScMgAlO ₄
Orientation	[0001] or [10-10] <±0.5°
Parallel	10″
Perpendicular	5′
surface Quality	10/5
Wavefront Distortion	λ/4@632nm
Surface Flatness	λ/8@632nm
Clear Aperture	>95%
Chamfer	<0.1×45°
Thickness/Diameter Tolerance	±0.05 mm
Maximum dimensions	dia 50×100mm
Coatings	AR/AR@940+1030; HR@1030+HT@940+AR1030
Coatings	

